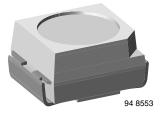


Vishay Semiconductors

High Speed Infrared Emitting Diode, 870 nm, GaAlAs Double Hetero



DESCRIPTION

VSMF4710 is an infrared, 870 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a PLCC-2 package for surface mounting (SMD).

FEATURES

- · Package type: surface mount
- Package form: PLCC-2
- Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75
- Peak wavelength: $\lambda_p = 870 \text{ nm}$
- · High reliability
- · High radiant power
- · High radiant intensity
- Angle of half intensity: $\phi = \pm 60^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- High modulation band width: $f_c = 24$ MHz
- · Good spectral matching with Si photodetectors
- Floor life: 168 h, MSL 3, acc. J-STD-020
- · Lead (Pb)-free reflow soldering
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Find out more about Vishay's Automotive Grade Product requirements at: www.vishay.com/applications

APPLICATIONS

- High speed IR data transmission
- High power emitter for low space applications
- High performance transmissive or reflective sensors

PRODUCT SUMMARY

COMPONENT	l _e (mW/sr)	φ (deg)	λ p (nm)	t _r (ns)
VSMF4710	10	± 60	870	15

Note

Test conditions see table "Basic Characteristics"

OPDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMF4710-GS08	Tape and reel	MOQ: 7500 pcs, 1500 pcs/reel	PLCC-2	
VSMF4710-GS18	Tape and reel	MOQ: 8000 pcs, 8000 pcs/reel	PLCC-2	

Note

MOQ: minimum order quantity



GREEN

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^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

VSMF4710

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	А	
Power dissipation		Pv	160	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	Acc. figure 8, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, soldered on PCB	R _{thJA}	250	K/W	

Note

 T_{amb} = 25 °C, unless otherwise specified

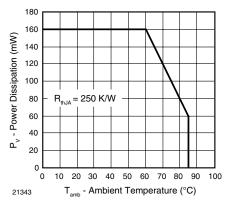
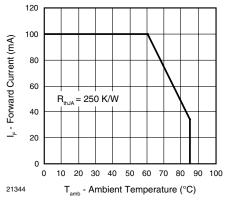


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature





PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 100 mA, t _p = 20 ms	V _F		1.5	1.8	V
Forward voltage	I _F = 1 A, t _p = 100 μs	V _F		2.3		V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		- 1.8		mV/K
Reverse current	V _R = 5 V	I _R			10	μA
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	Cj		125		pF
	I _F = 100 mA, t _p = 20 ms	l _e	6	10	22	mW/sr
Radiant intensity	I _F = 1 A, t _p = 100 μs	l _e		100	22	mW/sr
Radiant power	I _F = 100 mA, t _p = 20 ms	φ _e		40		mW
Temperature coefficient of ϕ_{e}	I _F = 100 mA	TKφ _e		- 0.35		%/K
Angle of half intensity		φ		± 60		deg
Peak wavelength	I _F = 100 mA	λρ		870		nm
Spectral bandwidth	I _F = 100 mA	Δλ		40		nm
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλρ		0.25		nm/K
Rise time	I _F = 100 mA	t _r		15		ns
Fall time	I _F = 100 mA	t _f		15		ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f _c		24		MHz
Virtual source diameter		d		0.44		mm

Note

T_{amb} = 25 °C, unless otherwise specified



High Speed Infrared Emitting Diode, Vishay Semiconductors 870 nm, GaAlAs Double Hetero

BASIC CHARACTERISTICS

 $T_{amb} = 25$ °C, unless otherwise specified

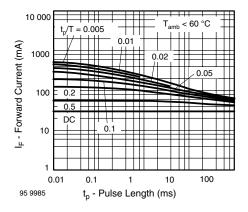


Fig. 3 - Pulse Forward Current vs. Pulse Duration

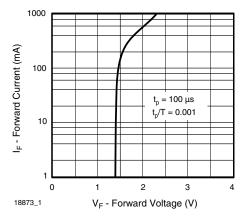


Fig. 4 - Forward Current vs. Forward Voltage

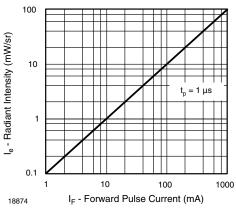


Fig. 5 - Radiant Intensity vs. Forward Current

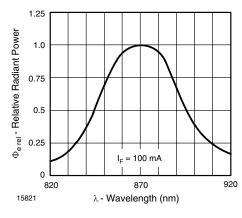


Fig. 6 - Relative Radiant Power vs. Wavelength

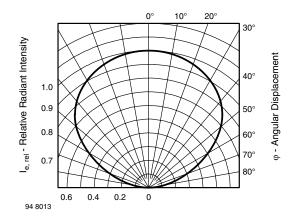
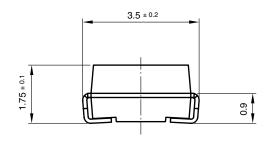


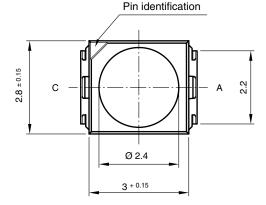
Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

Vishay Semiconductors High Speed Infrared Emitting Diode, 870 nm, GaAlAs Double Hetero



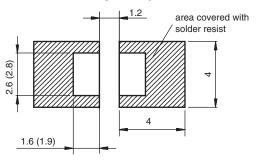
PACKAGE DIMENSIONS in millimeters





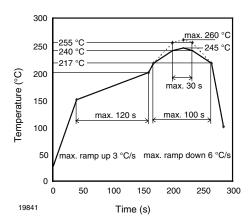
technical drawings according to DIN specifications

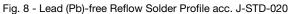
Mounting Pad Layout



Drawing-No.: 6.541-5067.01-4 Issue: 5; 04.11.08 20541

SOLDER PROFILE





DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 168 h Conditions: $T_{amb} < 30$ °C, RH < 60 % Moisture sensitivity level 3, acc. to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



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TAPE AND REEL

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.

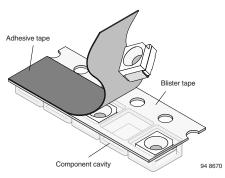


Fig. 9 - Blister Tape

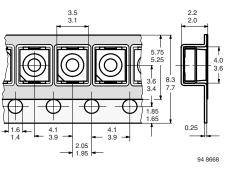
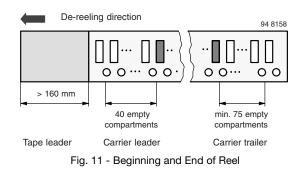


Fig. 10 - Tape Dimensions in mm for PLCC-2

MISSING DEVICES

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.



The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartments. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartments and sealed with cover tape.

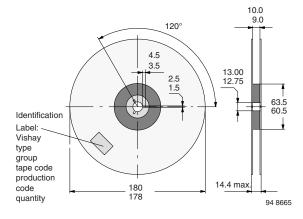
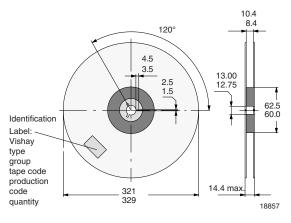


Fig. 12 - Dimensions of Reel-GS08





COVER TAPE REMOVAL FORCE

The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of 180° with regard to the feed direction.



Vishay

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